



SGM3699

0.5Ω, Low Voltage Quad, SPDT Analog Switch

GENERAL DESCRIPTION

The SGM3699 is a quad, low on-resistance, low voltage, bidirectional, single-pole/double-throw (SPDT) CMOS analog switch that is designed to operate from a single +1.8V to +4.2V power supply. Targeted applications include battery powered equipment that benefit from low R_{ON} (0.5Ω) and fast switching speeds ($t_{ON} = 52ns$, $t_{OFF} = 25ns$).

The SGM3699 consists of four SPDT switches. It is configured as a dual double-pole/double-throw (DPDT) device with two logic control inputs that control two SPDT switches each. The configuration can be used as a dual differential 2-to-1 multiplexer/demultiplexer.

SGM3699 is available in a TQFN-16 and SO-16 packages.

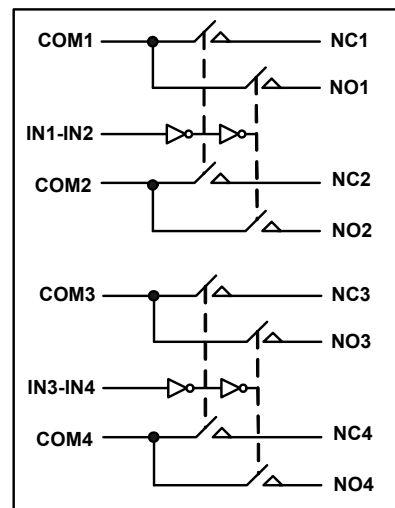
APPLICATIONS

- Communication Systems
- Cell Phones
- Portable Instrumentation
- Audio Signal Routing
- Audio and Video Switching
- PCMCIA Cards
- Computer Peripherals
- Modems
- PDA's

FEATURES

- Low Voltage Operation: 1.8V to 4.2V
- Low On-Resistance: 0.5Ω (TYP)
- Low On-Resistance Flatness
- -3dB Bandwidth: 70MHz
- Fast Switching Times (4.2V)
 - t_{ON} 52ns
 - t_{OFF} 25ns
- Rail-to-Rail Operation
- Typical Power Consumption (<0.01μW)
- TTL/CMOS Compatible
- Lead (Pb) Free TQFN-16 and SO-16 Packages

BLOCK DIAGRAM



ORDERING INFORMATION

| MODEL | PIN-PACKAGE | SPECIFIED TEMPERATURE RANGE | ORDERING NUMBER | PACKAGE MARKING | PACKAGE OPTION |
|---------|------------------|-----------------------------|-----------------|-----------------|---------------------|
| SGM3699 | TQFN-16(3mm×3mm) | -40°C to +85°C | SGM3699YTQ16/TR | 3699TQ | Tape and Reel, 3000 |
| | SO-16 | -40°C to +85°C | SGM3699YS16/TR | SGM3699YS16 | Tape and Reel, 2500 |

ABSOLUTE MAXIMUM RATINGS

V₊ to GND.....0V to 4.6V
 Analog, Digital voltage range ⁽¹⁾..... -0.3V to (V₊) + 0.3V
 Continuous Current NO, NC, or COM±200mA
 Peak Current NO, NC, or COM±350mA
 Operating Temperature Range.....-40°C to +85°C
 Junction Temperature.....150°C
 Storage Temperature.....-65°C to +150°C
 Lead Temperature (soldering, 10s).....260°C
 ESD Susceptibility
 HBM.....4000V
 MM.....400V

NOTE:

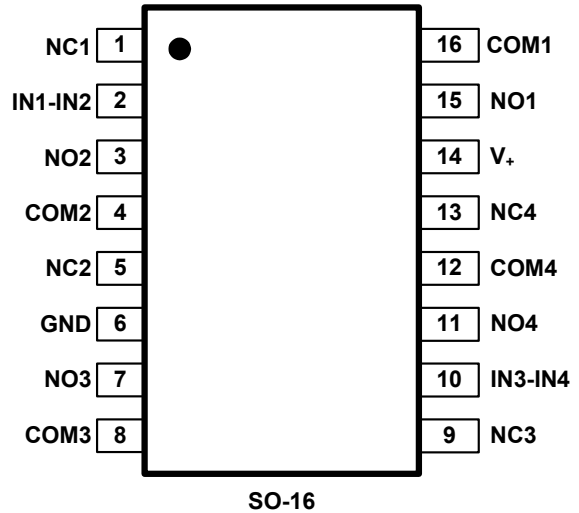
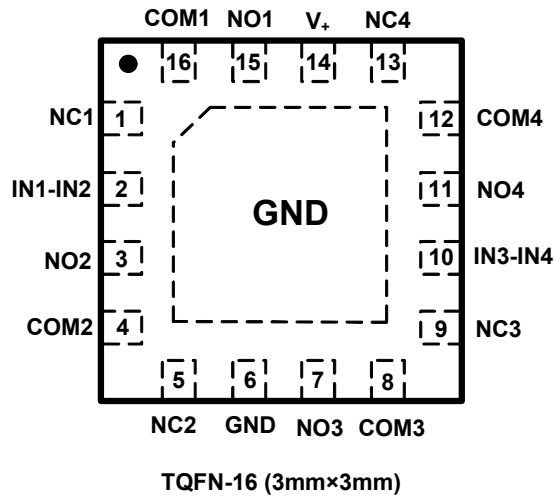
(1) Signals on NC, NO, or COM or IN_x exceeding V₊ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

(2) Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PIN CONFIGURATIONS (TOP VIEW)



PIN DESCRIPTION

| NAME | PIN | | FUNCTION |
|------------------|----------------------|--------------|---|
| | TQFN-16 (3mm×3mm) | SO-16 | |
| V ₊ | 14 | 14 | Power supply |
| GND | 6 | 6 | Ground |
| IN _x | 2, 10 | 2, 10 | Digital control pin to connect the COM terminal to the NO or NC terminals |
| COM _x | 16, 4, 8, 12 | 16, 4, 8, 12 | Common terminal |
| NO _x | 15, 3, 7, 11 | 15, 3, 7, 11 | Normally-open terminal |
| NC _x | 1, 5, 9, 13 | 1, 5, 9, 13 | Normally-closed terminal |

Note: NO_x, NC_x and COM_x terminal may be an input or output.

FUNCTION TABLE

| IN1-IN2 | FUNCTION | |
|---------|-------------|-------------|
| | NC1 and NC2 | NO1 and NO2 |
| 0 | ON | OFF |
| 1 | OFF | ON |

| IN3-IN4 | FUNCTION | |
|---------|-------------|-------------|
| | NC3 and NC4 | NO3 and NO4 |
| 0 | ON | OFF |
| 1 | OFF | ON |

ELECTRICAL CHARACTERISTICS

($V_+ = +4.2V$, $GND = 0V$, $V_{IH} = +1.6V$, $V_{IL} = +0.6V$, $T_A = -40^\circ C$ to $+85^\circ C$. Typical values are at $V_+ = +4.2V$, $T_A = +25^\circ C$, unless otherwise noted.)

| PARAMETER | SYMBOL | CONDITIONS | TEMP | MIN | TYP | MAX | UNITS |
|--------------------------------------|---------------------------------------|--|----------------|-------|------|-------|-------|
| ANALOG SWITCH | | | | | | | |
| Analog Signal Range | V_{NO}, V_{NC}, V_{COM} | | -40°C to +85°C | 0 | | V_+ | V |
| On-Resistance | R_{ON} | $V_+ = 4.2V$, V_{NO} or $V_{NC} = 1V$, $I_{COM} = -100mA$, Test Circuit 1 | +25°C | | 0.5 | 0.75 | Ω |
| | | | -40°C to +85°C | | | 0.85 | Ω |
| On-Resistance Match Between Channels | ΔR_{ON} | $V_+ = 4.2V$, V_{NO} or $V_{NC} = 1V$, $I_{COM} = -100mA$, Test Circuit 1 | +25°C | | 0.05 | 0.15 | Ω |
| | | | -40°C to +85°C | | 0.1 | 0.2 | Ω |
| On-Resistance Flatness | $R_{FLAT(ON)}$ | $V_+ = 4.2V$, V_{NO} or $V_{NC} = 1V, 2.5V$, $I_{COM} = -100mA$, Test Circuit 1 | +25°C | | 0.1 | 0.22 | Ω |
| | | | -40°C to +85°C | | | 0.26 | Ω |
| Source OFF Leakage Current | $I_{NC(OFF)}, I_{NO(OFF)}$ | $V_+ = 4.2V$, V_{NO} or $V_{NC} = 3.3V/ 0.3V$, $V_{COM} = 0.3V/ 3.3V$ | -40°C to +85°C | | | 1 | μA |
| Channel ON Leakage Current | $I_{NC(ON)}, I_{NO(ON)}, I_{COM(ON)}$ | $V_+ = 4.2V$, $V_{COM} = 0.3V/ 3.3V$, V_{NO} or $V_{NC} = 0.3V/ 3.3V$, or floating | -40°C to +85°C | | | 1 | μA |
| DIGITAL INPUTS | | | | | | | |
| Input High Voltage | V_{INH} | | -40°C to +85°C | 1.6 | | | V |
| Input Low Voltage | V_{INL} | | -40°C to +85°C | | | 0.5 | V |
| Input Leakage Current | I_{IN} | $V_+ = 4.2V$, $V_{IN} = 0V$ or $4.2V$ | -40°C to +85°C | | | 1 | μA |
| DYNAMIC CHARACTERISTICS | | | | | | | |
| Turn-On Time | t_{ON} | $V_+ = 4.2V$, V_{NO} or $V_{NC} = 2.0V$, $R_L = 50\Omega$, $C_L = 35pF$, Test Circuit 2 | +25°C | | 52 | | ns |
| Turn-Off Time | t_{OFF} | | +25°C | | 25 | | ns |
| Charge Injection | Q | $C_L = 1.0nF$, $V_G = 0V$, $R_G = 0\Omega$, Test Circuit 3 | +25°C | | 30 | | pC |
| Break-Before-Make Time Delay | t_D | V_{NO} or $V_{NC} = 1.5V$, $R_L = 50\Omega$, $C_L = 35pF$, Test Circuit 4 | +25°C | | 8 | | ns |
| Off Isolation | O_{ISO} | Signal = 0dBm, V_{NO} or V_{NC} centered between V_+ and GND $R_L = 50\Omega$, Test Circuit 5 | f = 100kHz | +25°C | | -75 | dB |
| | | | f = 1MHz | +25°C | | -55 | |
| Channel-to-Channel Crosstalk | X_{TALK} | Signal = 0dBm, Test Circuit 6 | f = 1MHz | +25°C | | -103 | dB |
| | | | f = 10MHz | +25°C | | -65 | |
| -3dB Bandwidth | BW | Signal = 0dBm, Test Circuit 7 | +25°C | | 70 | | MHz |
| Channel ON Capacitance | $C_{NC(ON)}, C_{NO(ON)}, C_{COM(ON)}$ | f = 1MHz | +25°C | | 80 | | pF |
| POWER REQUIREMENTS | | | | | | | |
| Power Supply Range | V_+ | | -40°C to +85°C | 1.8 | | 4.2 | V |
| Power Supply Current | I_+ | $V_+ = 4.2V$, $V_{IN} = 0V$ or V_+ | -40°C to +85°C | | | 1 | μA |

Specifications subject to changes without notice.

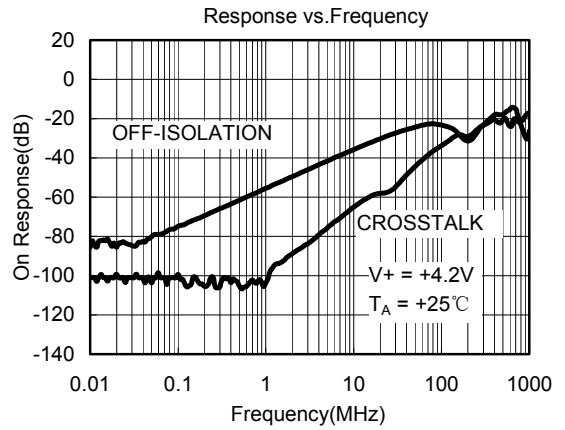
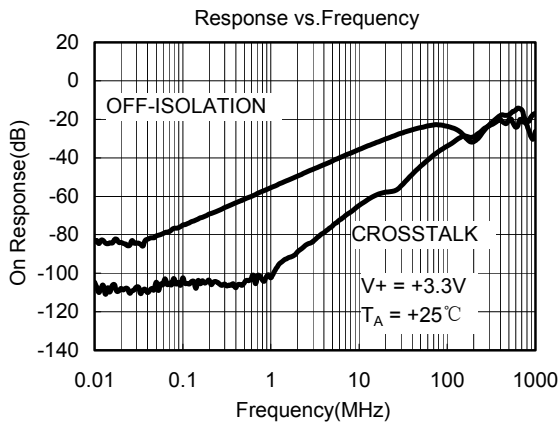
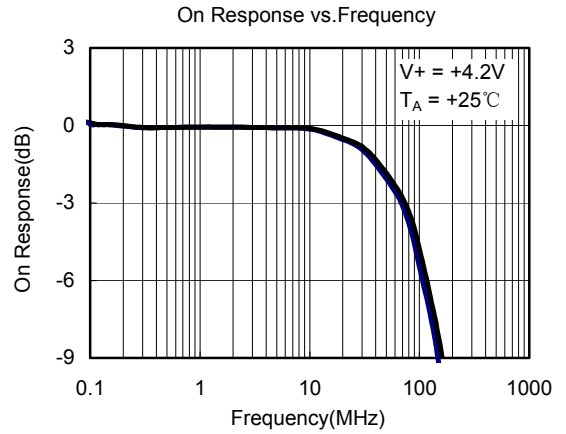
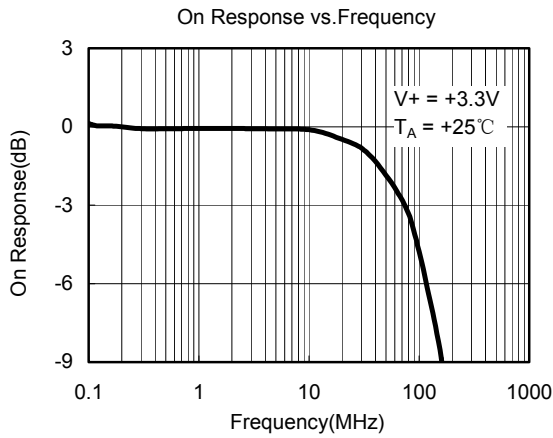
ELECTRICAL CHARACTERISTICS

(V_+ = +2.7 to +3.6V, GND = 0V, V_{IH} = +1.6 V, V_{IL} = +0.4V, T_A = -40°C to +85°C. Typical values are at V_+ = +3.0V, T_A = +25°C, unless otherwise noted.)

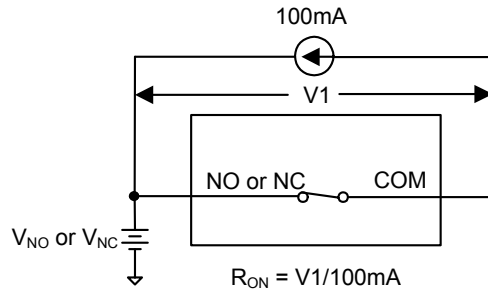
| PARAMETER | SYMBOL | CONDITIONS | TEMP | MIN | TYP | MAX | UNITS |
|---|--|--|----------------|-------|------|-------|-------|
| ANALOG SWITCH | | | | | | | |
| Analog Signal Range | V_{NO}, V_{NC}, V_{COM} | | -40°C to +85°C | 0 | | V_+ | V |
| On-Resistance | R_{ON} | V_+ = 2.7V, V_{NO} or V_{NC} = 1V, I_{COM} = -100mA, Test Circuit 1 | +25°C | | 0.6 | 0.9 | Ω |
| | | | -40°C to +85°C | | | 1 | Ω |
| On-Resistance Match Between Channels | ΔR_{ON} | V_+ = 2.7V, V_{NO} or V_{NC} = 1V, I_{COM} = -100mA, Test Circuit 1 | +25°C | | 0.15 | 0.2 | Ω |
| | | | -40°C to +85°C | | 0.15 | 0.24 | Ω |
| On-Resistance Flatness | $R_{FLAT(ON)}$ | V_+ = 2.7V, V_{NO} or V_{NC} = 1V, 2.5V, I_{COM} = -100mA, Test Circuit 1 | +25°C | | 0.05 | 0.15 | Ω |
| | | | -40°C to +85°C | | 0.1 | 0.2 | Ω |
| Source OFF Leakage Current | $I_{NC(OFF)}, I_{NO(OFF)}$ | V_+ = 3.6V, V_{NO} or V_{NC} = 3.3V/ 0.3V, V_{COM} = 0.3V/ 3.3V | -40°C to +85°C | | | 1 | μA |
| Channel ON Leakage Current | $I_{NC(ON)}, I_{NO(ON)},$ $I_{COM(ON)}$ | V_+ = 3.6V, V_{COM} = 0.3V/ 3.3V, V_{NO} or V_{NC} = 0.3V/ 3.3V, or floating | -40°C to +85°C | | | 1 | μA |
| DIGITAL INPUTS | | | | | | | |
| Input High Voltage | V_{INH} | | -40°C to +85°C | 1.5 | | | V |
| Input Low Voltage | V_{INL} | | -40°C to +85°C | | | 0.4 | V |
| Input Leakage Current | I_{IN} | V_+ = 2.7V, V_{IN} = 0V or 2.7V | -40°C to +85°C | | | 1 | μA |
| DYNAMIC CHARACTERISTICS | | | | | | | |
| Turn-On Time | t_{ON} | V_+ = 3.3V, V_{NO} or V_{NC} = 2.0V, R_L = 50Ω, C_L = 35pF, Test Circuit 2 | +25°C | | 54 | | ns |
| Turn-Off Time | t_{OFF} | | +25°C | | 38 | | ns |
| Charge Injection | Q | C_L = 1.0nF, V_G = 0V, R_G = 0Ω Test Circuit 3 | +25°C | | 26 | | pC |
| Break-Before-Make Time Delay | t_D | V_{NO} or V_{NC} = 1.5V, R_L = 50Ω, C_L = 35pF, Test Circuit 4 | +25°C | | 12 | | ns |
| Off Isolation | O_{ISO} | Signal = 0dBm, V_{NO} or V_{NC} centered between V_+ and GND , R_L = 50Ω, Test Circuit 5 | f = 100kHz | +25°C | | -75 | dB |
| | | | f = 1MHz | +25°C | | -55 | |
| Channel-to-Channel Crosstalk | X_{TALK} | Signal = 0dBm, Test Circuit 6 | f = 1MHz | +25°C | | -103 | dB |
| | | | f = 10MHz | +25°C | | -65 | |
| -3dB Bandwidth | BW | Signal = 0dBm, Test Circuit 7 | +25°C | | 70 | | MHz |
| Channel ON Capacitance | $C_{NC(ON)}, C_{NO(ON)},$ $C_{COM(ON)}$ | f = 1MHz | +25°C | | 80 | | pF |

Specifications subject to changes without notice.

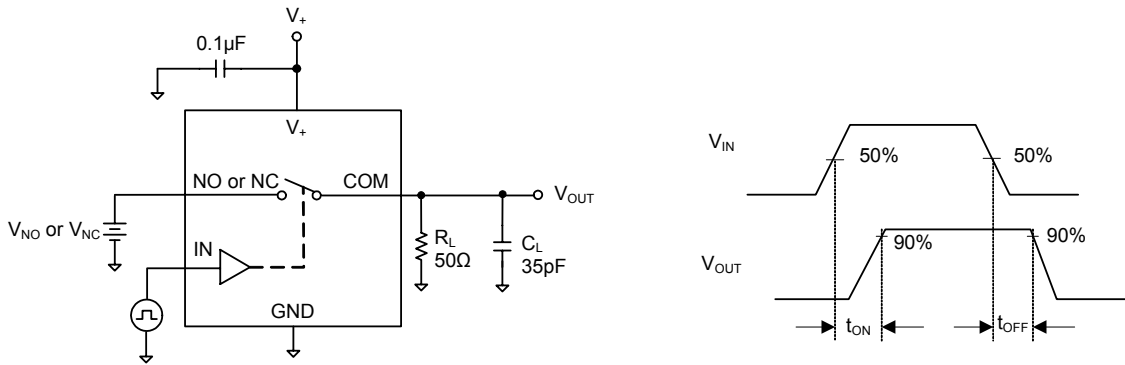
TYPICAL PERFORMANCE CHARACTERISTICS



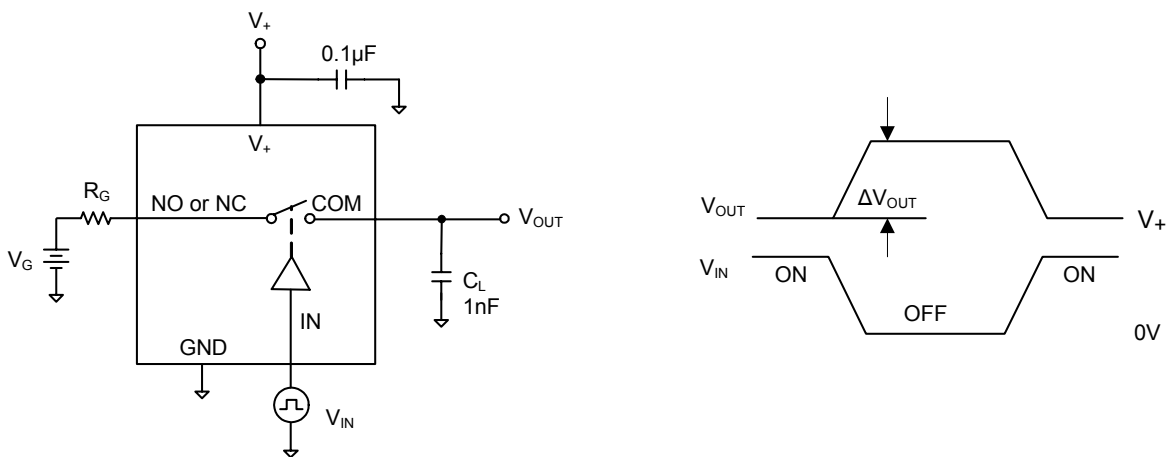
TEST CIRCUITS



Test Circuit 1. On Resistance

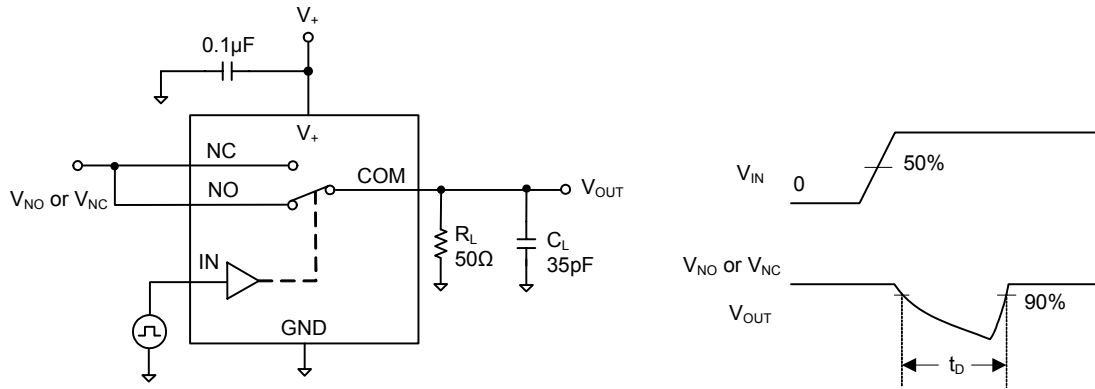


Test Circuit 2. Switching Times

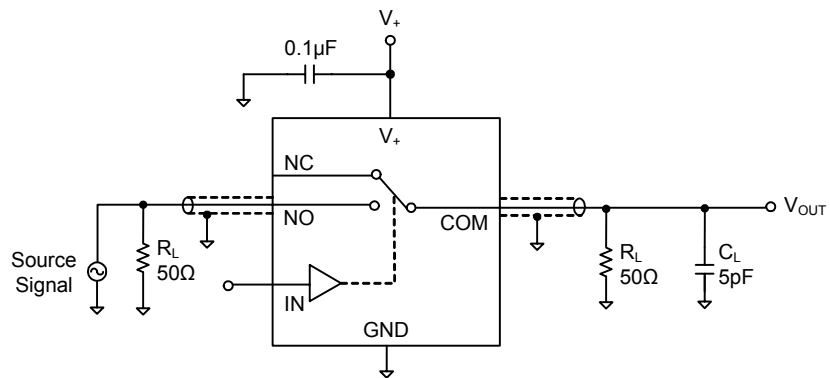


Test Circuit 3. Charge Injection

TEST CIRCUITS (Cont.)

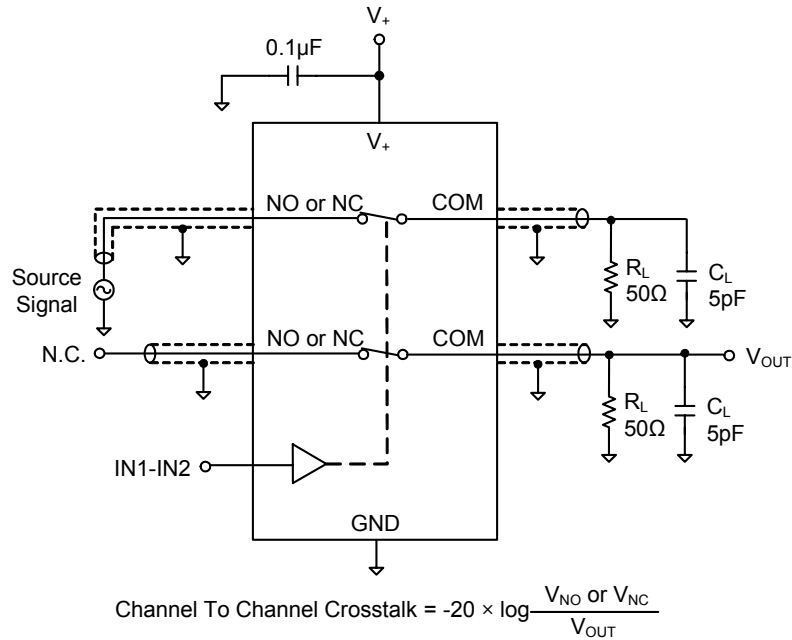


Test Circuit 4. Break-Before-Make Time Delay, t_D

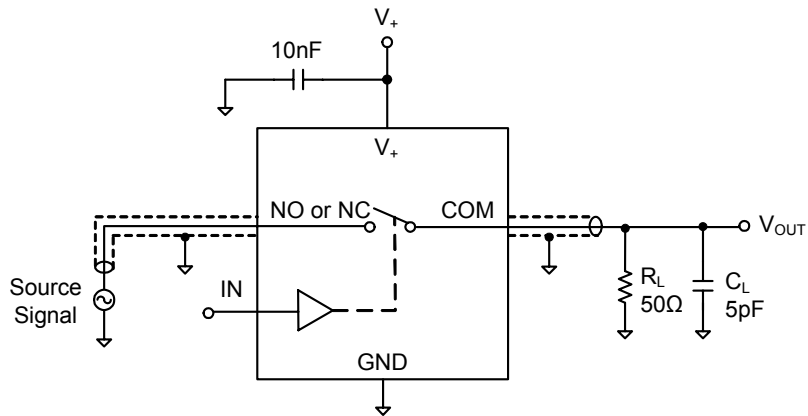


Test Circuit 5. Off Isolation

TEST CIRCUITS (Cont.)



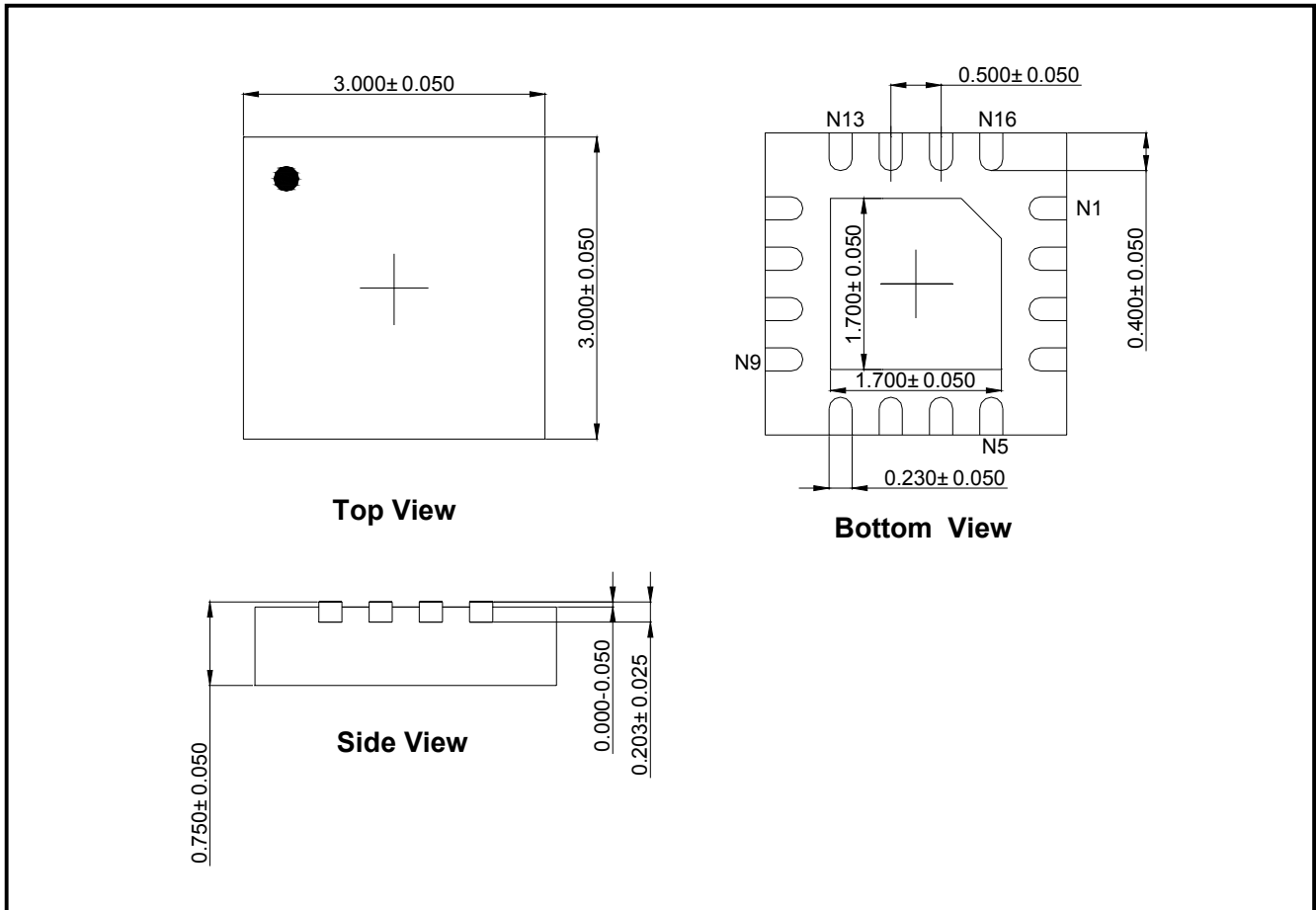
Test Circuit 6. Channel-to-Channel Crosstalk



Test Circuit 7. -3dB Bandwidth

PACKAGE OUTLINE DIMENSIONS

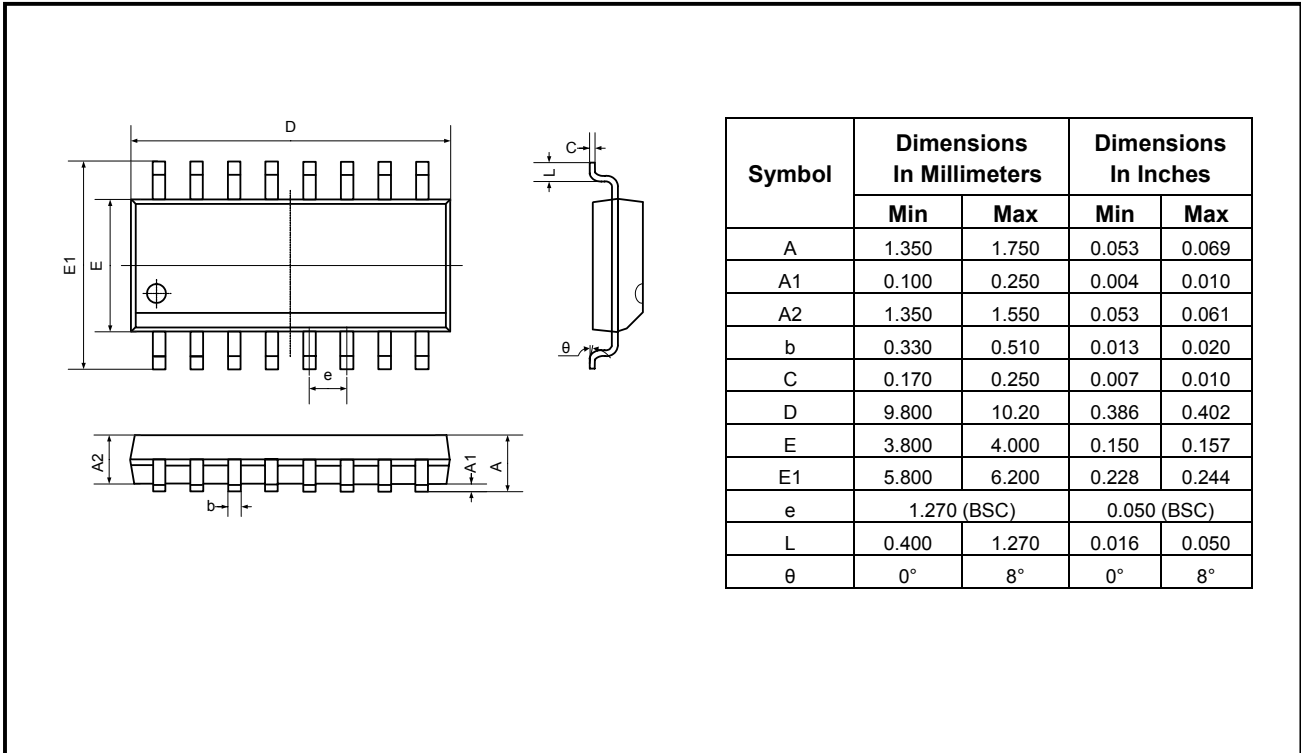
TQFN-16 (3mm × 3mm)



NOTE: All linear dimensions are in millimeters.

PACKAGE OUTLINE DIMENSIONS

SO-16



07/2009 REV. B. 2

SGMICRO is dedicated to provide high quality and high performance analog IC products to customers. All SGMICRO products meet the highest industry standards with strict and comprehensive test and quality control systems to achieve world-class consistency and reliability.

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